



SR802 - SR815 8.0 AMPS. Schottky Barrier Rectifiers

DO-201AD

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Features

- ♦ Low power loss, high efficiency.
- ♦ High current capability, Low VF.
- ♦ High reliability
- High surge current capability.
- ♦ Epitaxial construction.
- ♦ Guard-ring for transient protection.
- For use in low voltage, high frequency inventor, free wheeling, and polarity protection application
- Green compound with suffix "G" on packing code & prefix "G" on datecode.

Mechanical Data

- ♦ Cases: DO-201AD molded plastic
- Lead: Pure tin plated, lead free., solderable per MIL-STD-202, Method 208 guaranteed
- ♦ Polarity: Color band denotes cathode
- High temperature soldering guaranteed: 260°C/10 seconds/.375",(9.5mm) lead lengths at 5 lbs., (2.3kg) tension
- ♦ Weight: 1.10 grams

.220 (5.6) .197 (5.0) DIA. .052 (1.3) .048 (1.2) DIA.

Dimensions in inches and (millimeters)

Marking Diagram



SR8XX = Specific Device Code

Version: D10

G = Green Compound Y = Year

WW = Work Week

Maximum Ratings and Electrical Characteristics

Rating at 25 °C ambient temperature unless otherwise specified. Single phase, half wave, 60 Hz, resistive or inductive load.

For capacitive load, derate current by 20%

Type Number		Symbol	SR 802	SR 803	SR 804	SR 805	SR 806	SR 809	SR 810	SR 815	Units
Maximum Recurrent Peak Reverse Voltage		VRRM	20	30	40	50	60	90	100	150	V
Maximum RMS Voltage		VRMS	14	21	28	35	42	63	70	105	V
Maximum DC Blocking Voltage		VDC	20	30	40	50	60	90	100	150	V
Maximum Average Forward Rectified Current See Fig. 1		I F(AV)	8.0							Α	
Peak Forward Surge Current, 8.3 ms Single Half Sine-wave Superimposed on Rated Load (JEDEC method)		IFSM	150							А	
Maximum Instantaneous Forward Voltage @8.0A		VF	0.55 0.70			0.	0.92 1.0		V		
Maximum D.C. Reverse Current @ T _A =25			0.5					0.1			mA
at Rated DC Blocking Voltage (Note 1)	00°C	I R	15			10		-			mA
@ T _A =12	25°C		_				5			mA	
Typical Junction Capacitance (Note 2)		Cj	500		2	70		165		рF	
Typical Thermal Resistance (Note 3)		Reja	40						°C/W		
Operating Junction Temperature Range		TJ	-65 to +125 -65 to +150				°C				
Storage Temperature Range		Тѕтс	-65 to +150								°C

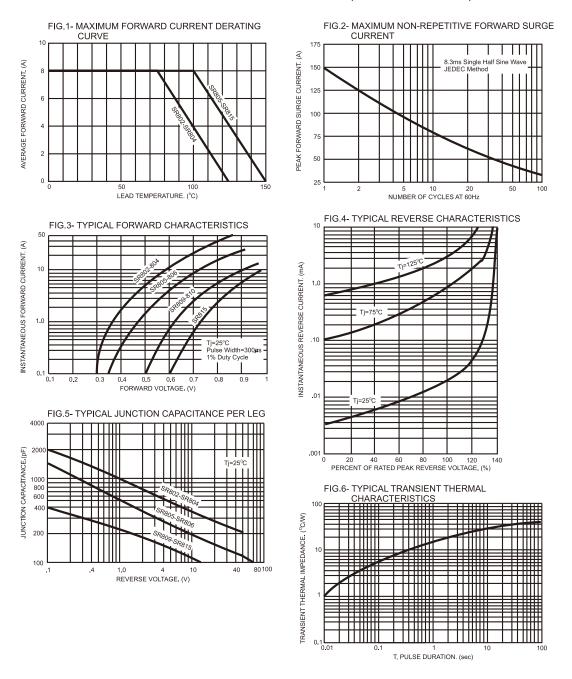
Notes: 1. Pulse Test with PW=300 usec, 1% Duty Cycle

2. Measured at 1 MHz and Applied Reverse Voltage of 4.0V D.C.

3. Mount on Cu-Pad Size 16mm x 16mm on P.C.B.



RATINGS AND CHARACTERISTIC CURVES (SR802 THRU SR815)



Version: D10